



# MIE1W0505BGLVH

5V, 1W, Regulated, 2.5kV<sub>RMS</sub>  
Isolated DC/DC Module

## DESCRIPTION

The MIE1W0505BGLVH is an isolated, regulated, DC/DC module. It can support 3V to 5.5V input voltage ( $V_{IN}$ ) applications. With excellent load and line regulation, it supports up to 1W of output power ( $P_{OUT}$ ).

The MIE1W0505BGLVH integrates power MOSFETs, transformer, and feedback (FB) circuit all in one chip, achieving excellent performance and saving size.

The MIE1W0505BGLVH supports a regulated output voltage ( $V_{OUT}$ ). When  $V_{OUT}$  drops below the target voltage (3.3V or 5V), the IC begins switching, delivering power from the  $V_{IN}$  pin to the  $V_{OUT}$  pin until  $V_{OUT}$  reaches the target voltage again.

The device also integrates a  $V_{OUT}$  feedback block, which can regulate  $V_{OUT}$  without the need for a traditional optocoupler and a precision programmable reference IC. This small solution provides high reliability compared to traditional isolated power modules.

Full protection features include short-circuit protection (SCP) and over-temperature protection (OTP).

The MIE1W0505BGLVH is available in a small LGA-12 (4mmx5mm) package.

## FEATURES

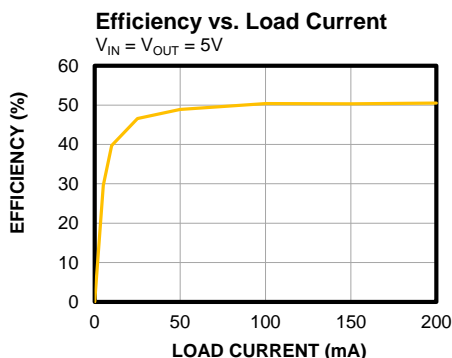
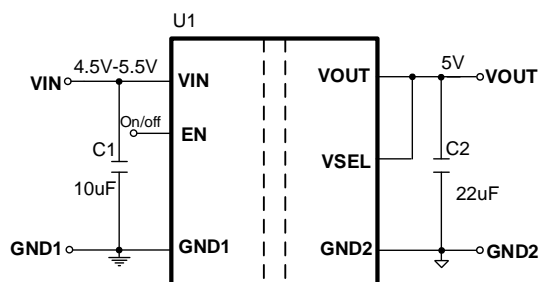
- 3V to 5.5V Input Voltage ( $V_{IN}$ ) Operation Range
- Selectable 5V or 3.3V Output Voltage ( $V_{OUT}$ )
  - 5V to 5V:  $\geq 200\text{mA}$  Available Load Current ( $I_{LOAD}$ )
  - 5V to 3.3V:  $\geq 200\text{mA}$  Available  $I_{LOAD}$
  - 3.3V to 3.3V:  $\geq 75\text{mA}$  Available  $I_{LOAD}$
- 2.5kV<sub>RMS</sub> Isolation Voltage
- Supports Infinite Capacitive Load
- 0.4% Load Regulation
- 0.3% Line Regulation
- Continuous Short-Circuit Protection (SCP)
- Over-Temperature Protection (OTP)
- CB Certification According to IEC 62368-1
- Meets EN55032 Class B Emissions
- -40°C to +125°C Operating Temperature Range
- Available in an LGA-12 (4mmx5mm) Package

## APPLICATIONS

- Industrial Automation Systems
- Isolated Bias Power for Digital Isolators
- Isolated Power for Isolated RS-485, RS-422, and CAN Interfaces
- Isolated Sensor Power Supplies
- Telecom and Network Devices (5G RRUs, Industrial CPEs, Network Gateways, etc.)

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## TYPICAL APPLICATION



## ORDERING INFORMATION

Part Number*	Package	Top Marking	MSL Rating
MIE1W0505BGLVH-3R	LGA-12 (4mmx5mm)	See Below	3

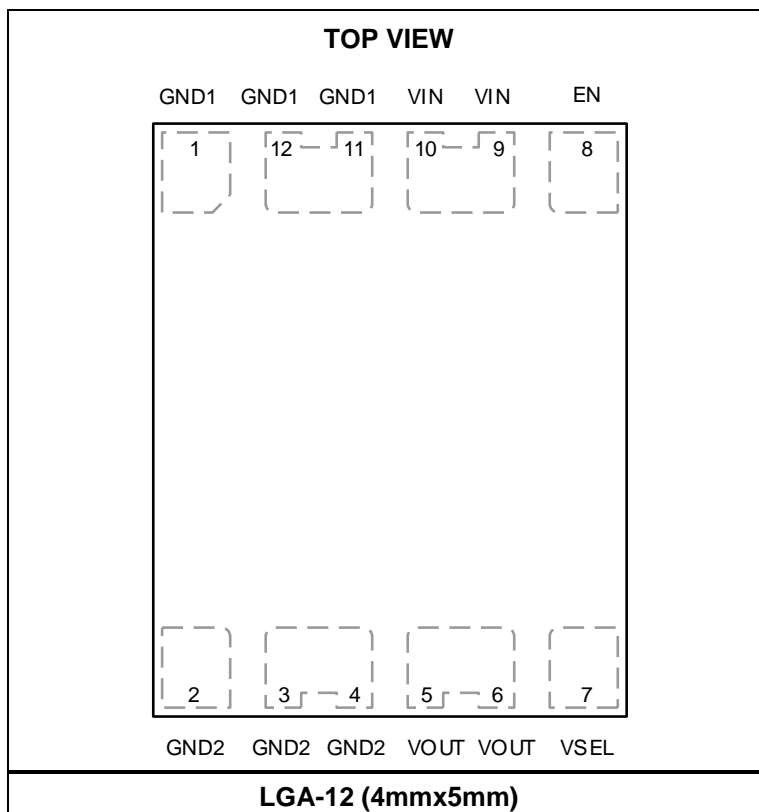
\* For Tape & Reel, add suffix -Z (e.g. MIE1W0505BGLVH-3R-Z).

## TOP MARKING

**MPSYWW**  
**1W0505**  
**LLLLLL**  
**BH**

MPS: MPS prefix  
Y: Year code  
WW: Week code  
1W0505: Part number  
LLLLLL: Lot number  
BH: Part number suffix

## PACKAGE REFERENCE



## PIN FUNCTIONS

Pin #	Name	Description
1, 11, 12	GND1	<b>Power ground side 1.</b>
2, 3, 4	GND2	<b>Power ground side 2.</b>
5, 6	VOUT	<b>Power output pin.</b> It is recommended to connect a 22μF capacitor and a 0.1μF capacitor between VOUT and GND2 (pins 3 and 4) to decrease the output voltage (V <sub>OUT</sub> ) ripple and noise.
7	VSEL	<b>Output voltage setting pin.</b> For a 5V output, connect the VSEL pin to VOUT or float this pin. For a 3.3V output, connect the VSEL pin to GND2. Do not bias VSEL with another power source.
8	EN	<b>Enable pin.</b> Pull the EN pin high to enable the MIE1W0505BGLVH; pull it low to disable the MIE1W0505BGLVH. Do not leave this pin floating.
9, 10	VIN	<b>Power input pin.</b> Connect the VIN pin to a 3V to 5.5V power supply. Connect a 10μF capacitor and a 0.1μF capacitor between VIN and GND1 (pins 11 and 12) to stabilize the IC.

## ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>

VIN/EN to GND1 ..... -0.3V to +6.5V  
VOUT/VSEL to GND2 ..... -0.3V to +6.5V  
Continuous power dissipation (T<sub>A</sub> = 25°C) <sup>(2)</sup> <sup>(4)</sup>  
..... 1.78W  
Junction temperature (T<sub>J</sub>) ..... 150°C  
Lead temperature ..... 260°C  
Storage temperature ..... -65°C to +150°C

## ESD Ratings

Human body model (HBM) ..... ±5000V  
Charged-device model (CDM) ..... ±2000V

## Recommended Operating Conditions <sup>(3)</sup>

Input voltage (V<sub>IN</sub>) ..... 3V to 5.5V  
Output voltage (V<sub>OUT</sub>) ..... 5/3.3V  
Operating junction temp (T<sub>J</sub>) .... -40°C to +125°C

## Thermal Resistance

θ<sub>JA</sub>    θ<sub>JC</sub>

LGA-12 (4mmx5mm)

EV1W0505B-LVH-00A <sup>(4)</sup> ..... 70 ..... 22... °C/W

JESD51-7 <sup>(5)</sup> ..... 61 ..... 19... °C/W

## Notes:

- Exceeding these ratings may damage the device.
- The maximum allowable power dissipation is a function of the maximum junction temperature T<sub>J</sub> (MAX), the junction-to-ambient thermal resistance θ<sub>JA</sub>, and the ambient temperature T<sub>A</sub>. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P<sub>D</sub> (MAX) = (T<sub>J</sub> (MAX) - T<sub>A</sub>) / θ<sub>JA</sub>. Exceeding the maximum allowable power dissipation can produce an excessive die temperature, which may cause the regulator to go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- Measured on the EV1W0505B-LVH-00A (51mmx51mm), a 1oz, 2-layer PCB.
- The value of θ<sub>JA</sub> given in this table is only valid for comparison with other packages and cannot be used for design purposes. These values were calculated in accordance with JESD51-7, and simulated on a specified JEDEC board. They do not represent the performance obtained in an actual application.

## ELECTRICAL CHARACTERISTICS

$V_{IN} = 5V$ ,  $V_{OUT} = 5V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$  <sup>(6)</sup>, typical values are tested at  $T_J = 25^{\circ}C$ , unless otherwise noted.

Parameter	Symbol	Condition	Min	Typ	Max	Units
<b>Power Supply</b>						
$V_{IN}$ under-voltage lockout (UVLO) rising threshold	$V_{IN\_UVLO\_R}$	$V_{IN}$ rising	2.45	2.6	2.75	V
$V_{IN}$ UVLO threshold hysteresis	$V_{IN\_HYS}$			220		mV
Shutdown current	$I_{SD}$	$V_{IN} = 5.5V$ , $V_{EN} = 0V$ , measured on the $V_{IN}$ pin		7	50	$\mu A$
Input current	$I_{IN}$	Load = 0A		8	11	mA
		Load = 0.2A		395	450	mA
EN input high threshold					2	V
EN input voltage low threshold			0.4			V
EN input current leakage		EN connected to GND1	-7	-5		$\mu A$
Output voltage accuracy	$V_{OUT\_ACC}$	$V_{IN} = 4.5V$ to $5.5V$ , $I_{OUT} = 0A$	4.85	5	5.15	V
Load regulation		Load = 0A to 0.2A		0.4	2	%
Line regulation		$V_{IN} = 4.5V$ to $5.5V$ , load = 0.2A		0.3	2	%
Efficiency <sup>(7)</sup>		Load = 0.2A		50.5		%
Ripple		$T_A = 25^{\circ}C$ , 20MHz bandwidth		60	100	mV
Isolated voltage	$V_{ISO}$	Short all primary pins and all secondary pins as a two-terminal part, test time = 60s, qualified test	2.5			kV <sub>RMS</sub>
		Short all primary pins and all secondary pins as a two-terminal part, test time = 1s, production test, 100% test	3			kV <sub>RMS</sub>
Input to output capacitance <sup>(7)</sup>	$C_{I-O}$	Short all primary pins and all secondary pins as a two-terminal part, measuring frequency = 1MHz		5		pF
Input to output resistance <sup>(7)</sup>	$R_{I-O}$	Short all primary pins and all secondary pins as a two-terminal part, test voltage = 500V <sub>DC</sub>	50			G $\Omega$
Static common-mode transient immunity (CMTI) <sup>(7)</sup>	CMTI		100			kV/ $\mu s$
<b>Thermal Shutdown <sup>(7)</sup></b>						
Thermal shutdown temperature	$T_{SD}$			150		$^{\circ}C$
Thermal shutdown hysteresis	$T_{SD-HYS}$			20		$^{\circ}C$

## ELECTRICAL CHARACTERISTICS *(continued)*

$V_{IN} = 5V$ ,  $V_{OUT} = 3.3V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$  <sup>(6)</sup>, typical values are tested at  $T_J = 25^{\circ}C$ , unless otherwise noted.

Parameter	Symbol	Condition	Min	Typ	Max	Units
<b>Power Supply</b>						
Shutdown current	$I_{SD}$	$V_{IN} = 5.5V$ , $V_{EN} = 0V$ , measured on the VIN pin		7	50	$\mu A$
Input current	$I_{IN}$	Load = 0A		5	8	mA
		Load = 0.2A		354	430	mA
EN input current leakage		EN connected to GND1	-7	-5		$\mu A$
Output voltage accuracy	$V_{OUT\_ACC}$	$V_{IN} = 4.5V$ to $5.5V$ , $I_{OUT} = 0A$	3.18	3.3	3.42	V
Load regulation		Load = 0A to 0.2A		0.4	2	%
Line regulation		$V_{IN} = 4.5V$ to $5.5V$ , load = 0.2A		0.2	2	%
Efficiency <sup>(7)</sup>		Load = 0.2A		37		%
Ripple		$T_A = 25^{\circ}C$ , 20MHz bandwidth		50	90	mV

## ELECTRICAL CHARACTERISTICS *(continued)*

$V_{IN} = 3.3V$ ,  $V_{OUT} = 3.3V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_J = -40^{\circ}C$  to  $+125^{\circ}C$  <sup>(6)</sup>, typical values are tested at  $T_J = 25^{\circ}C$ , unless otherwise noted.

Parameter	Symbol	Condition	Min	Typ	Max	Units
<b>Power Supply</b>						
Shutdown current	$I_{SD}$	$V_{EN} = 0V$ , measured on the VIN pin		5	30	$\mu A$
Input current	$I_{IN}$	Load = 0A		5	8	mA
		Load = 0.075A		150	190	mA
EN input current leakage		EN connected to GND1	-5	-3.3		$\mu A$
Output voltage accuracy	$V_{OUT\_ACC}$	$V_{IN} = 3V$ to $3.6V$ , $I_{OUT} = 0A$	3.18	3.3	3.42	V
Load regulation		Load = 0A to 0.075A		0.3	1.8	%
Line regulation		$V_{IN} = 3V$ to $3.6V$ , load = 0.075A		0.2	1.5	%
Efficiency <sup>(7)</sup>		Load = 0.075A		50		%
Ripple		$T_A = 25^{\circ}C$ , 20MHz bandwidth		30	60	mV

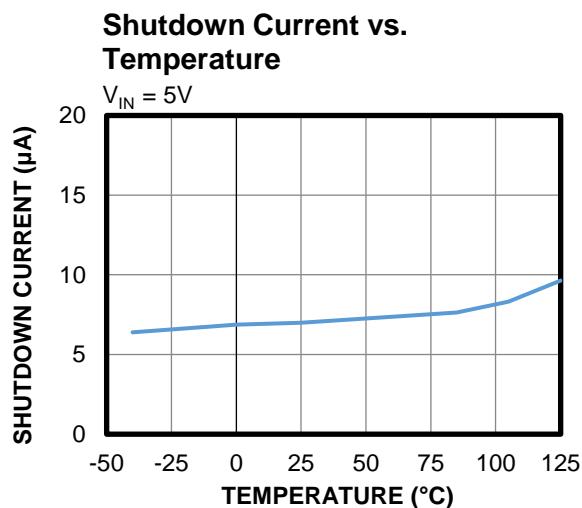
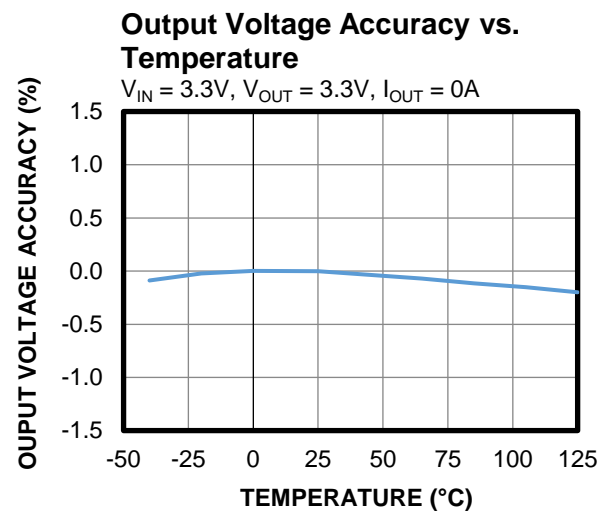
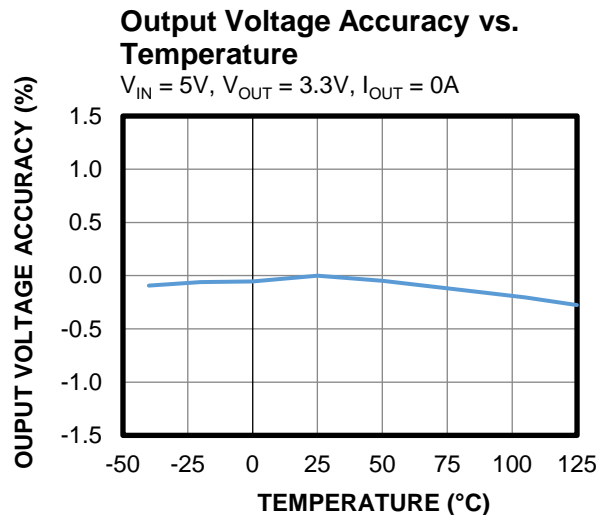
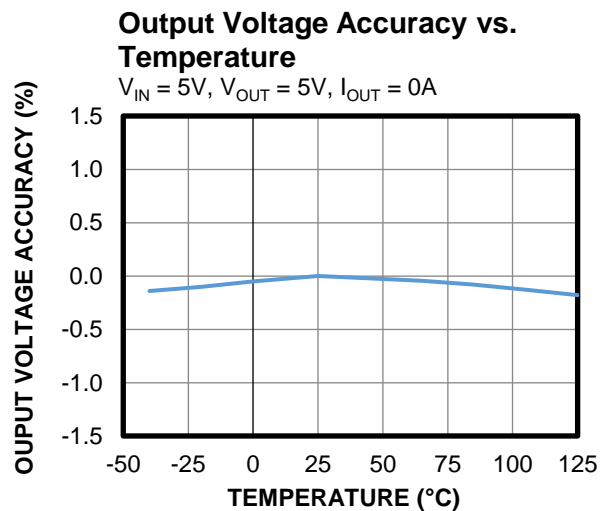
### Notes:

6) Guaranteed by over-temperature (OT) correlation. Not tested in production.

7) Guaranteed by sample characterization. Not tested in production.

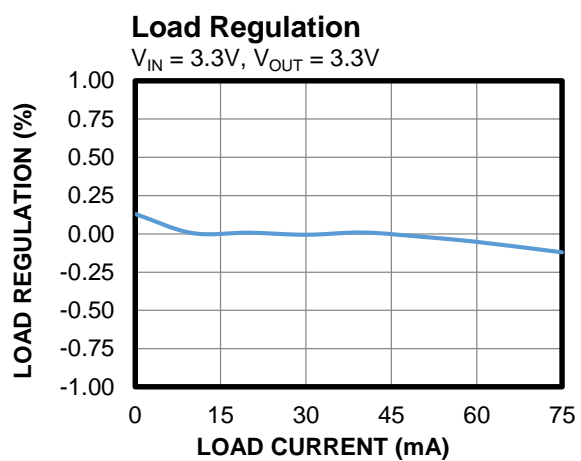
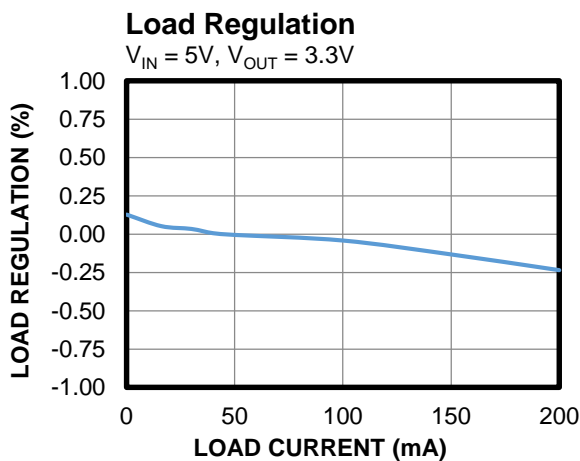
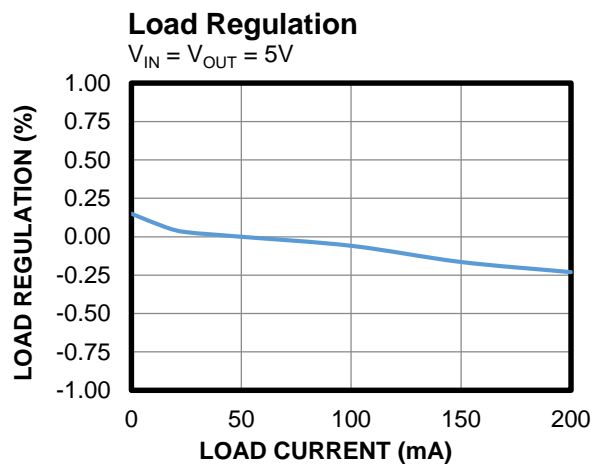
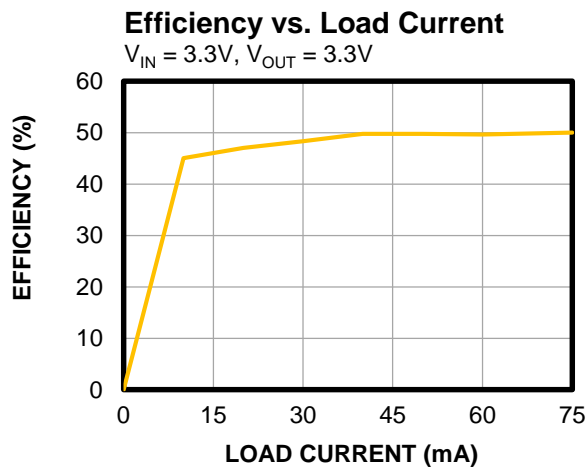
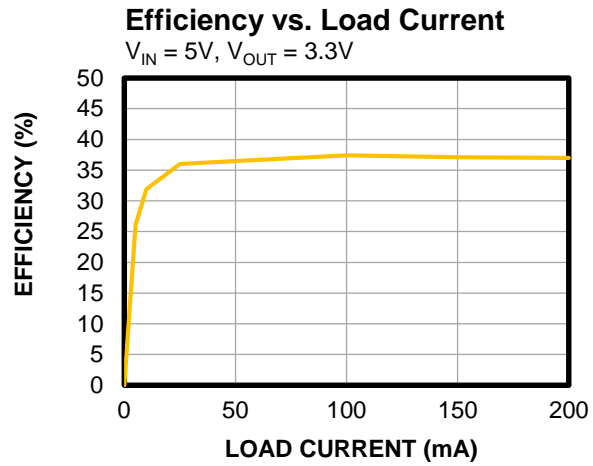
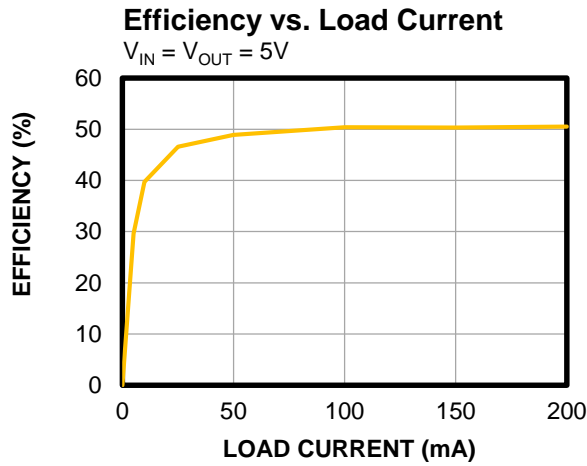
# TYPICAL CHARACTERISTICS

$V_{IN} = 5V$ ,  $V_{OUT} = 5V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_A = 25^\circ C$ , unless otherwise noted.



# TYPICAL PERFORMANCE CHARACTERISTICS

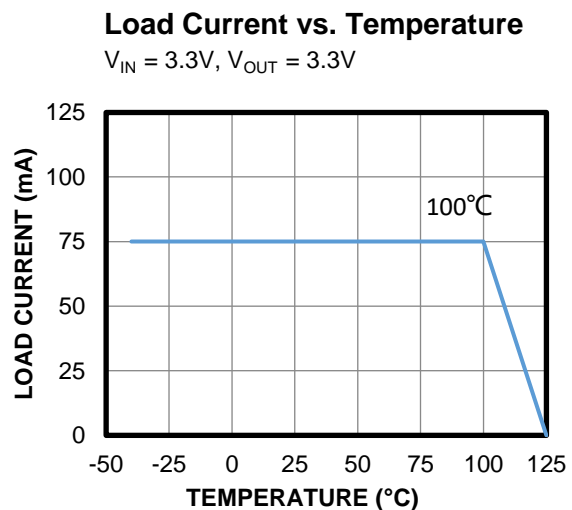
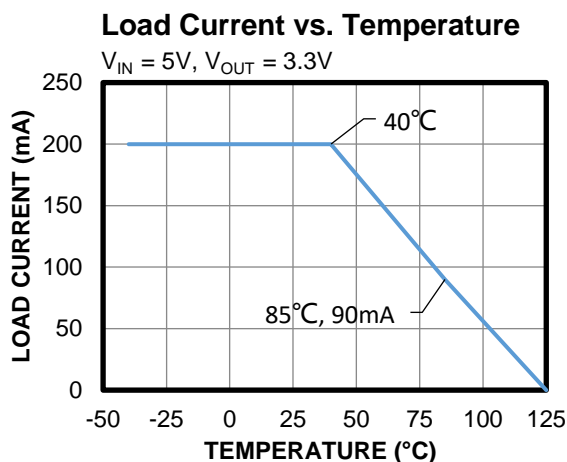
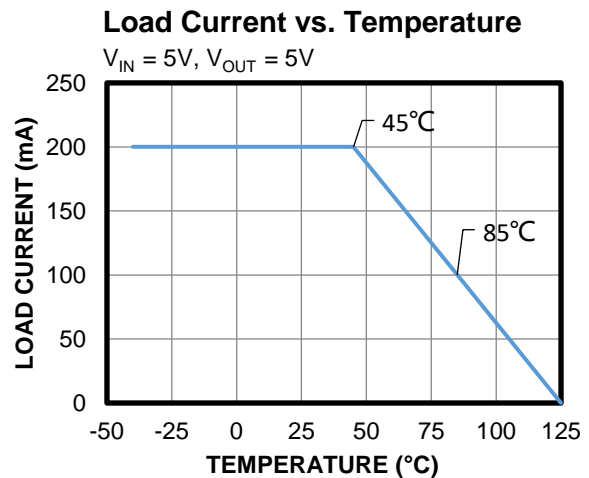
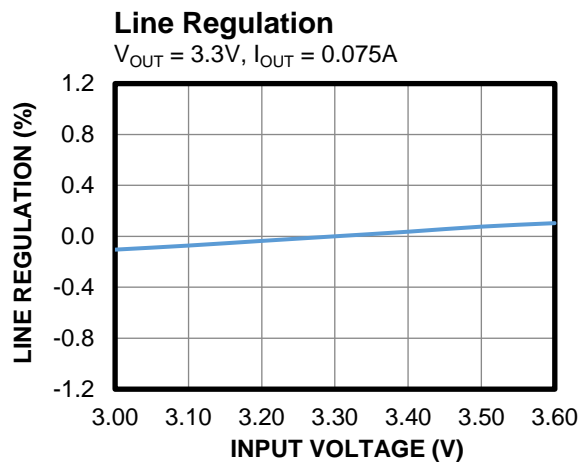
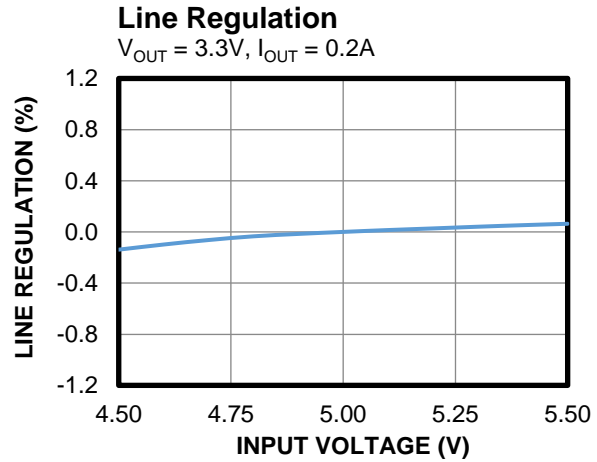
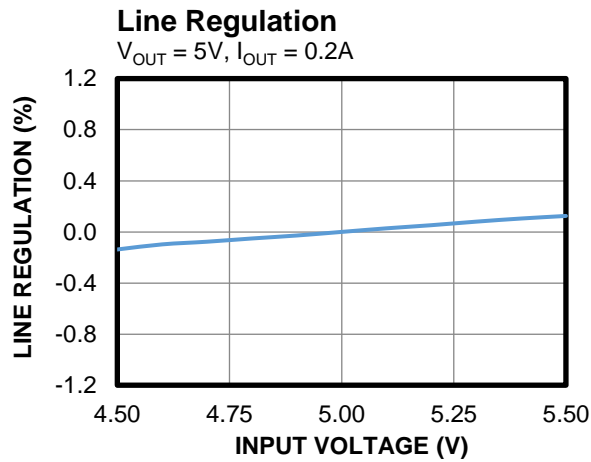
$V_{IN} = 5V$ ,  $V_{OUT} = 5V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_A = 25^\circ C$ , unless otherwise noted.





# TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$ ,  $V_{OUT} = 5V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

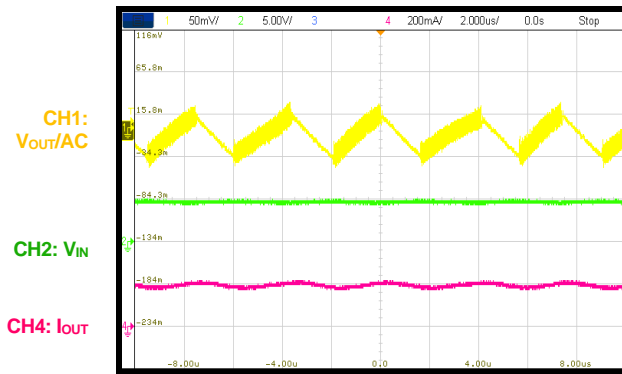


# TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$ ,  $V_{OUT} = 5V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

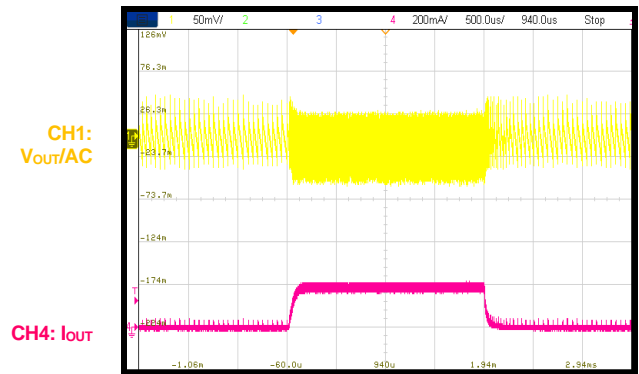
## $V_{OUT}$ Ripple

$I_{OUT} = 0.2A$



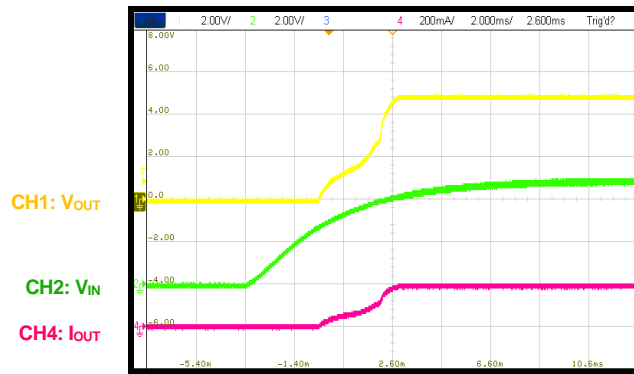
## Load Transient

$I_{OUT} = 0A$  to  $0.2A$



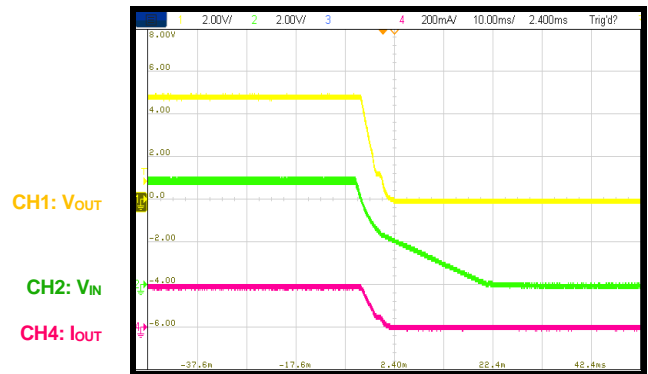
## Start-Up through $V_{IN}$

$I_{OUT} = 0.2A$



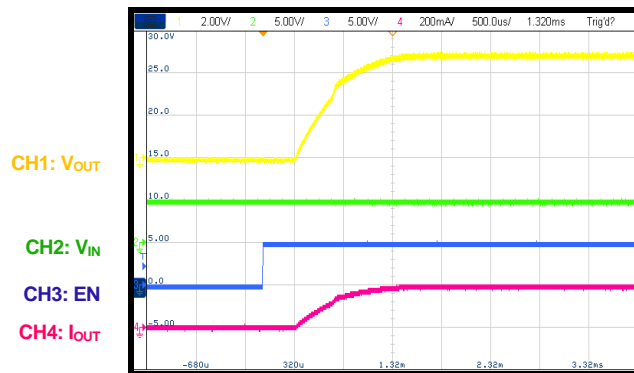
## Shutdown through $V_{IN}$

$I_{OUT} = 0.2A$



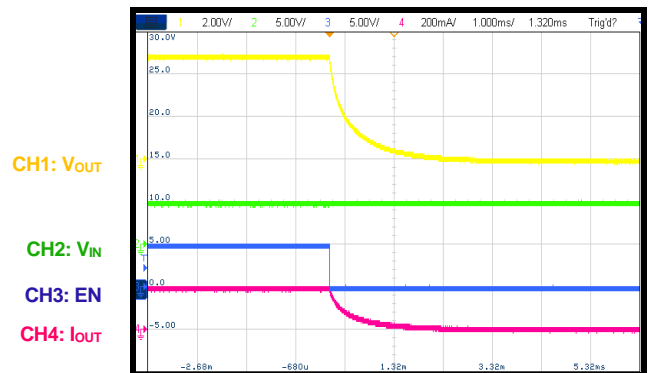
## Start-Up through EN

$I_{OUT} = 0.2A$



## Shutdown through EN

$I_{OUT} = 0.2A$

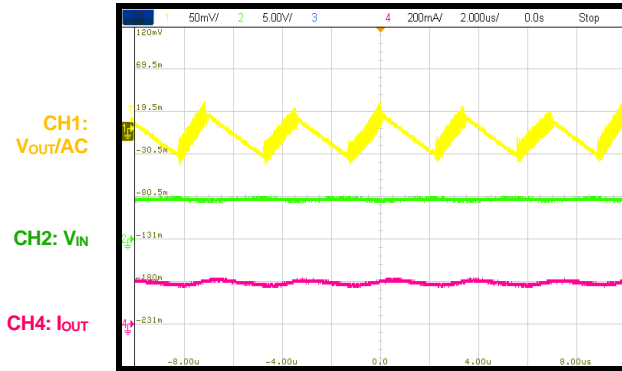


# TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$ ,  $V_{OUT} = 3.3V$ ,  $C_{IN} = 0.1\mu F + 10\mu F$ ,  $C_{OUT} = 0.1\mu F + 22\mu F$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

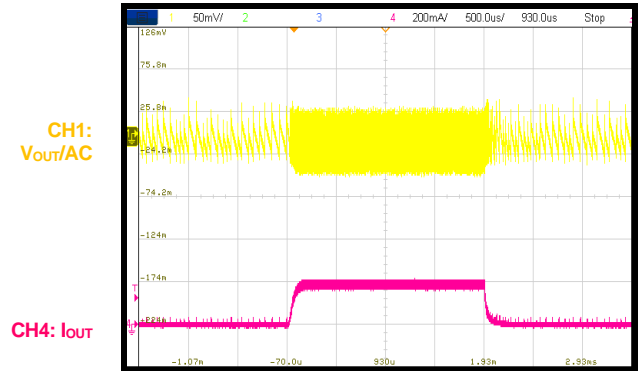
## $V_{OUT}$ Ripple

$I_{OUT} = 0.2A$



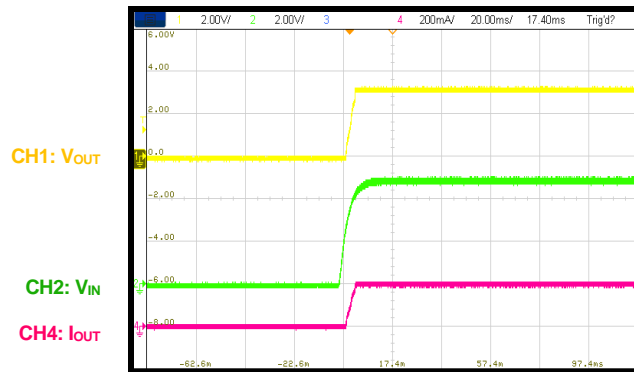
## Load Transient

$I_{OUT} = 0A$  to  $0.2A$



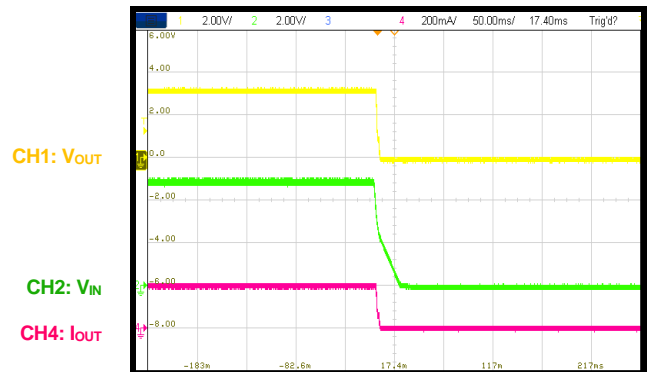
## Start-Up through $V_{IN}$

$I_{OUT} = 0.2A$



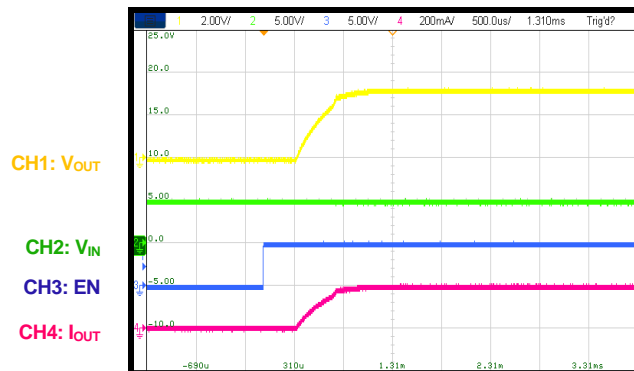
## Shutdown through $V_{IN}$

$I_{OUT} = 0.2A$



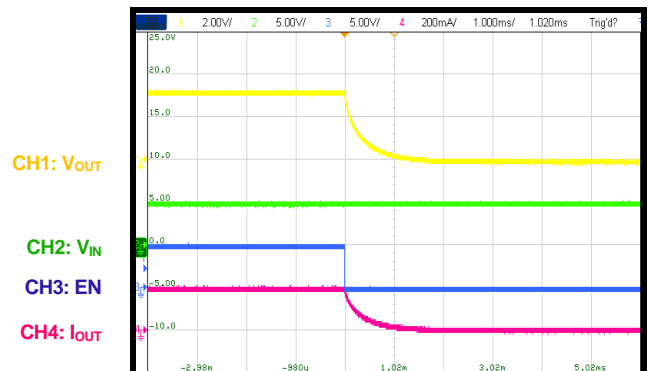
## Start-Up through EN

$I_{OUT} = 0.2A$



## Shutdown through EN

$I_{OUT} = 0.2A$



# FUNCTIONAL BLOCK DIAGRAM

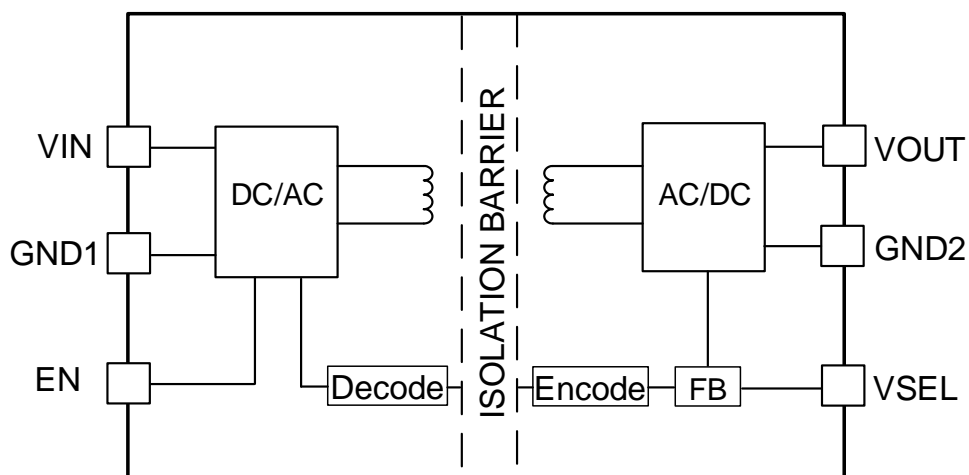


Figure 1: Functional Block Diagram

## OPERATION

The MIE1W0505BGLVH is a regulated, isolated DC/DC module that can support 3V to 5.5V input voltage ( $V_{IN}$ ) applications across a -40°C to +125°C operating temperature range. It has excellent load and line regulation, and supports up to 1W of output power ( $P_{OUT}$ ).

### Isolation Power Conversion

The MIE1W0505BGLVH integrates power MOSFETs, transformer, and feedback (FB) circuit all in one chip, making it a high-performance, small-sized solution.

If the output voltage ( $V_{OUT}$ ) is below the target voltage (3.3V or 5V), the IC starts switching to deliver power from  $V_{IN}$  to  $V_{OUT}$ . If  $V_{OUT}$  exceeds the target voltage, the device stops switching.

### Setting the Output Voltage

To set  $V_{OUT}$  to 5V, float the VSEL pin or connect it to VOUT. The VOUT pin can output a 200mA load with a 4.5V to 5.5V  $V_{IN}$  range.

To set  $V_{OUT}$  to 3.3V, connect the VSEL to GND2. The VOUT pin can output a 200mA load with a 4.5V to 5.5V  $V_{IN}$  range, or a 75mA load with a 3V to 3.6V  $V_{IN}$  range. VSEL logic is locked during start-up. After start-up,  $V_{OUT}$  is fixed even if the VSEL logic is changed.

### Under-Voltage Lockout Protection (UVLO)

The MIE1W0505BGLVH has input under-voltage lockout (UVLO) protection to ensure reliable  $P_{OUT}$ . The MIE1W0505BGLVH starts up once  $V_{IN}$  exceeds the UVLO rising threshold. The device shuts down when  $V_{IN}$  drops below the UVLO falling threshold. This function prevents the device from operating at an insufficient voltage. UVLO is a non-latch protection.

### Enable (EN)

The EN pin enables and disables the MIE1W0505BGLVH. When a voltage above 2V is applied to the EN pin and  $V_{IN}$  is above the  $V_{IN}$  UVLO threshold, the MIE1W0505BGLVH enables all functions and begins switching. If the EN voltage ( $V_{EN}$ ) falls below its lower threshold and (0.4V), switching is disabled. For automatic start-up, connect the EN pin to  $V_{IN}$  directly or through a resistor divider.

### Power Converter Soft Start (SS) and Short-Circuit Protection (SCP)

To avoid overshoot and inrush current during start-up, the MIE1W0505BGLVH has a built-in internal soft start (SS) function that gradually ramps up the output voltage ( $V_{OUT}$ ).

The MIE1W0505BGLVH starts up in constant current (CC) charging mode. In this mode, the current limit folds back, and  $I_{OUT}$  CC charges the output capacitor ( $C_{OUT}$ ) until  $V_{OUT}$  rises to about 2.7V. After the CC charging period, the MIE1W0505BGLVH's current limit returns to normal (does not fold back), with higher  $I_{OUT}$  capability. Such features guarantee infinite capacitive load.

During an overload or output short-circuit condition,  $V_{OUT}$  drops due to the internal current limit. Once  $V_{OUT}$  drops below about 2.2V, the MIE1W0505BGLVH enters CC charging mode. After the over-current (OC) or short-circuit is condition removed and  $V_{OUT}$  rises to about 2.7V, the MIE1W0505BGLVH resumes normal operation.

### Over-Temperature Protection (OTP)

The MIE1W0505BGLVH integrates one temperature monitoring circuit. If the junction temperature ( $T_J$ ) exceeds 150°C, the MIE1W0505BGLVH shuts down. Once the temperature drops below 130°C, the device restarts and resumes normal operation.

## APPLICATION INFORMATION

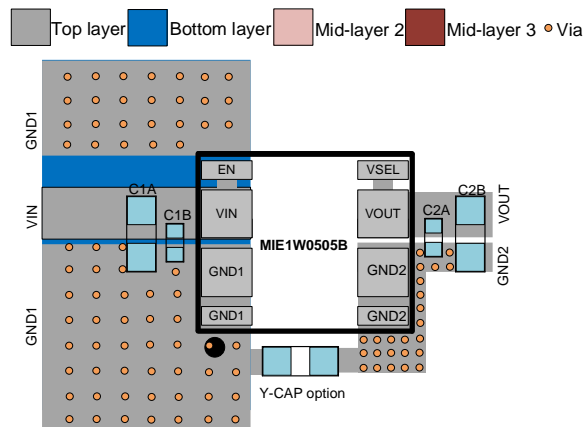
### Selecting the Input and Output Capacitors

For stable operation, connect decoupling capacitors between the VIN and GND1 pins at the input side, and between the VOUT and GND2 pins at the output side. Place these decoupling capacitors as close to VIN and VOUT as possible. It is recommended to add one 10µF and one 0.1µF ceramic capacitor at the input, and to add one 22µF and one 0.1µF ceramic capacitor at output side. The higher-value capacitor is used to make the V<sub>OUT</sub> ripple suitable, and the smaller one is used to filter high-frequency noise.

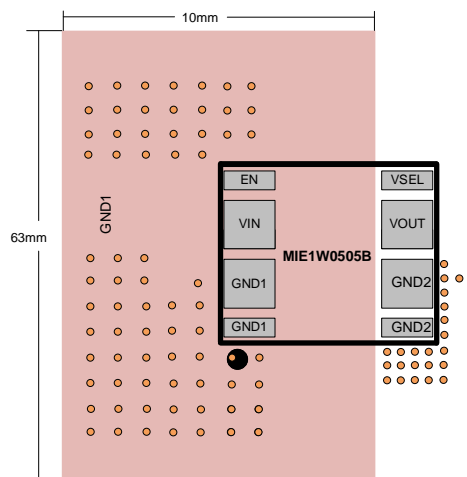
### PCB Layout Guidelines

Efficient PCB layout is critical for stable operation. A 4-layer layout is recommended for good EMI performance. For the best results, refer to Figure 2 and follow the guidelines below:

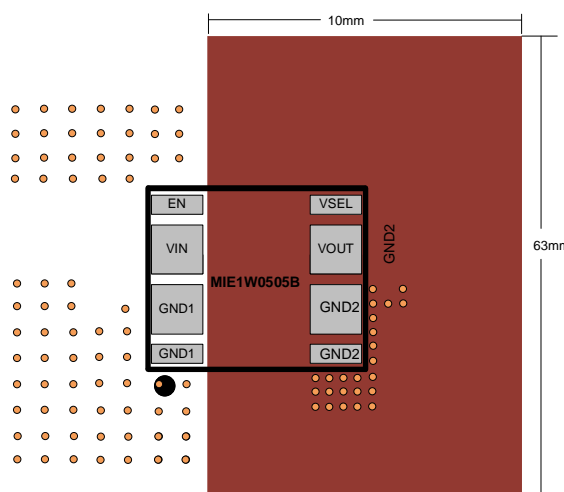
1. For safety, the primary side and secondary side should be physically separated. Ensure that the creepage/clearance meets the standards for the specified application.
2. To reduce output noise, minimize the loop area between VIN, the input capacitor, and GND1, as well as between VOUT, the output capacitor, and GND2.
3. Place enough copper and vias around the GND1 pins to improve thermal performance.
4. Do not place large copper areas on the GND2 and VOUT pins on the top layer, as doing so will make EMI worse. The smaller the copper areas on VOUT and GND2, the better the EMI performance.
5. Build a low-ESL overlap Y-capacitor to bypass EMI noise. Place sufficient vias on the GND1 and GND2 copper planes to reduce the Y-capacitor's ESL.
6. It is recommended to place the external Y-capacitor for EMI debugging. An SMD package for the Y-capacitor is recommended due to its lower ESL.



Top Layer and Bottom Layer



Mid-Layer 2



Mid-Layer 3

Figure 2: Recommended PCB Layout

## TYPICAL APPLICATION CIRCUITS

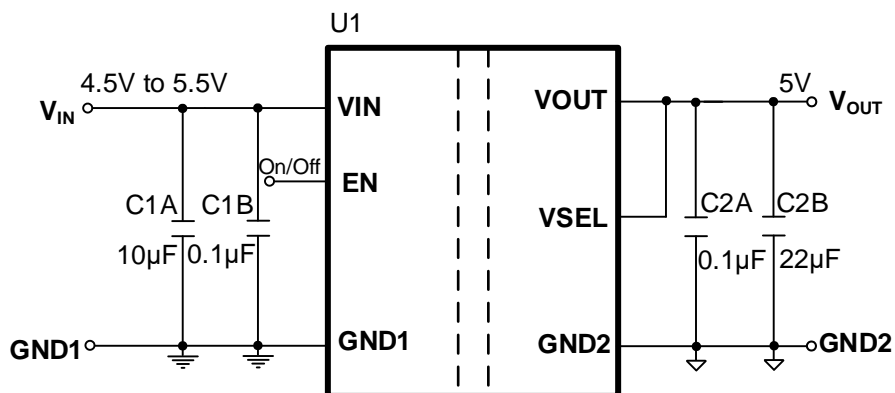


Figure 3: Typical Application Circuit with 5V Output

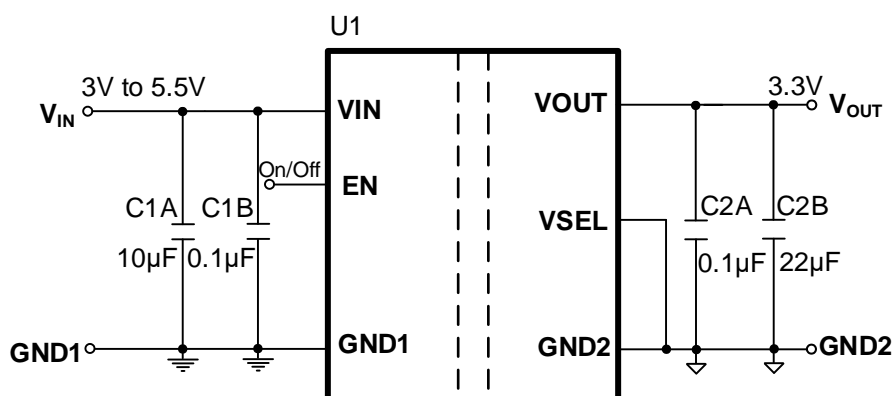
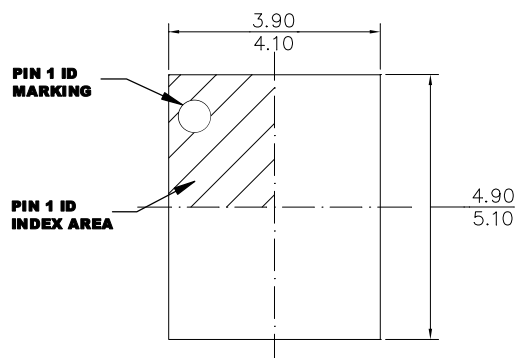


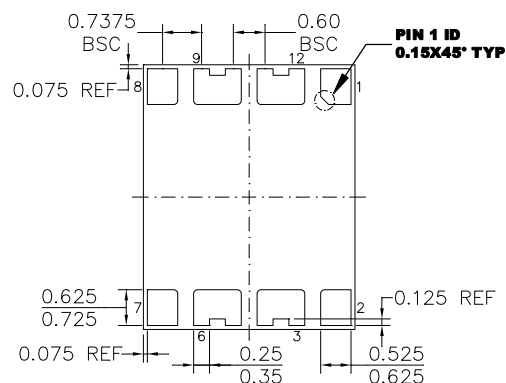
Figure 4: Typical Application Circuit with 3.3V Output

## PACKAGE INFORMATION

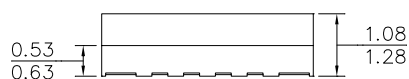
### LGA-12 (4mmx5mm)



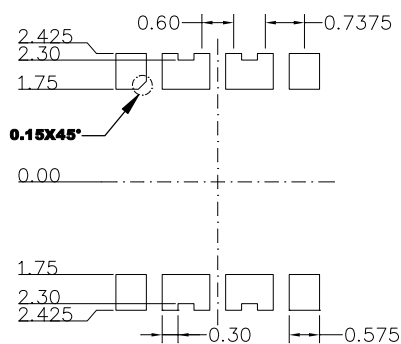
### TOP VIEW



### BOTTOM VIEW



### SIDE VIEW



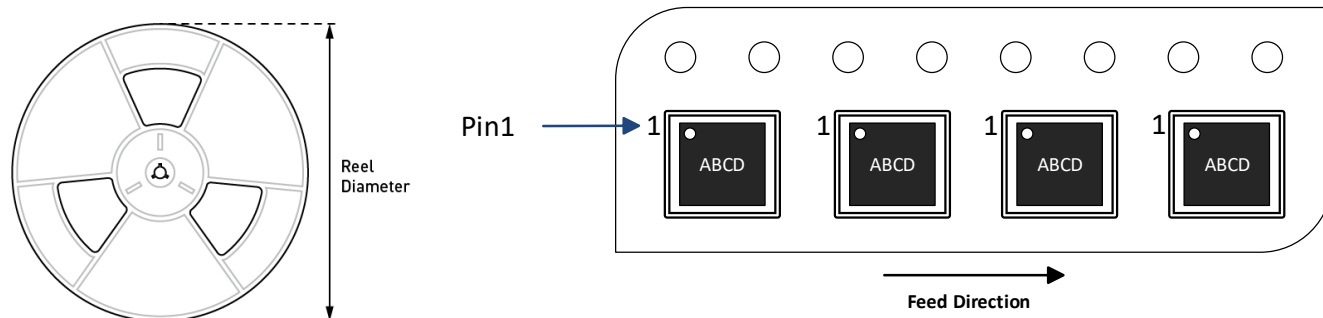
**NOTE:**

- 1) ALL DIMENSIONS ARE IN MILLIMETERS.**  
**2) LEAD COPLANARITY SHALL BE 0.10**  
**MILLIMETERS MAX.**  
**3) JEDEC REFERENCE IS MO-303.**  
**4) DRAWING IS NOT TO SCALE.**

## RECOMMENDED LAND PATTERN



# CARRIER INFORMATION



Part Number	Package Description	Quantity /Reel	Quantity /Tube	Quantity /Tray	Reel Diameter	Carrier Tape Width	Carrier Tape Pitch
MIE1W0505BGLVH-3R-Z	LGA-12 (4mmx5mm)	2500	N/A	N/A	13in	12mm	8mm



## REVISION HISTORY

Revision #	Revision Date	Description	Pages Updated
1.0	6/28/2024	Initial Release	-

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